

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	72	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and porous	US-PGPUB; USPAT	ADJ	ON	2006/06/07 16:14
L2	3	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same (GaN or (gallium adj nitride))) and (porous same (TiN or (titanium adj nitride)))	US-PGPUB; USPAT	ADJ	ON	2006/06/07 16:18
L3	0	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same (GaN or (gallium adj nitride))) and (porous same (TiN or (titanium adj nitride)))	USPAT	ADJ	ON	2006/06/07 16:18
L4	0	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same (GaN or (gallium adj nitride))) and (porous same (TiN or (titanium adj nitride)))	EPO	ADJ	ON	2006/06/07 16:18
L5	0	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same (GaN or (gallium adj nitride))) and (porous same (TiN or (titanium adj nitride)))	JPO	ADJ	ON	2006/06/07 16:18
L6	0	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same (GaN or (gallium adj nitride))) and (porous same (TiN or (titanium adj nitride)))	DERWENT	ADJ	ON	2006/06/07 16:18
L7	0	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same (GaN or (gallium adj nitride))) and (porous same (TiN or (titanium adj nitride)))	IBM_TDB	ADJ	ON	2006/06/07 16:19
L8	10	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same nitride) and (porous same (TiN or metal\$ or (titanium adj nitride)))	US-PGPUB	ADJ	ON	2006/06/07 16:24

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L9	3	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same nitride) and (porous same (TiN or (metal or metallic) or (titanium adj nitride)))	USPAT	ADJ	ON	2006/06/07 16:27
L10	0	((sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same nitride) and (porous same (TiN or (metal or metallic) or (titanium adj nitride))))).clms.	US-PGPUB	ADJ	ON	2006/06/07 16:28
L11	0	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same nitride) and (porous same (TiN or (metal or metallic) or (titanium adj nitride)))	DERWENT	ADJ	ON	2006/06/07 16:28
L12	0	(sapphire same substrate) and (GaN or (gallium adj nitride)) and (AlGaN or (aluminum adj gallium adj nitride)) and (porous same nitride) and (porous same (TiN or (metal or metallic) or (titanium adj nitride)))	EPO; JPO; IBM_TDB	ADJ	ON	2006/06/07 16:28